NSN 5962-01-317-0890

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View Online at https://aerobasegroup.com/nsn/5962-01-317-0890 **Overall Height:** 0.432 inches **Body Length:** 1.490 inches **Body Width:** Between 0.500 inches and 0.610 inches **Body Height:** Between 0.172 inches and 0.217 inches **Maximum Power Dissipation Rating:** 750.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Static operation and monolithic **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 20 input **Case Outline Source And Designator:** D-10 mil-m-38510 **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -1.0 volts power source and 7.0 volts power source **Memory Device Type:** Ram **Memory Capacity:** 512x8 **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 28 printed circuit Shelf Life: N/a

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Unit Of Measure:

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Demilitarization:

No

Fiig:

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